DPDT SWITCH GaAs MMIC

■ GENERAL DESCRIPTION

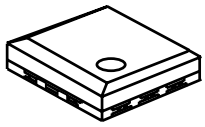
NJG1602HE3 is a GaAs high power DPDT switch MMIC for antenna switch of tri- and dual-mode cellular phone application such as CDMA, GPS and PCS.

This switch features low loss, high isolation at high power.

This device includes logic decoder function, and can be operated by 1 bit control signal for path switching.

The ultra small & ultra thin USB12 package is adopted.

■ PACKAGE OUTLINE

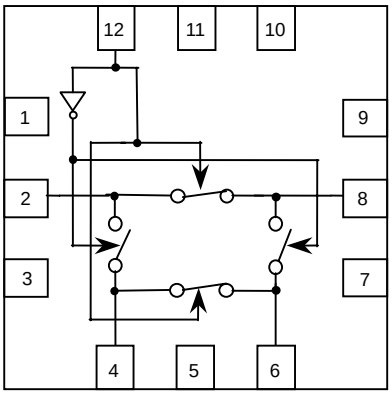


■ FEATURES

● Low voltage operation	+2.5V min.
● Pin at 0.2dBcompression point	36dBm typ. @f=0.9GHz, V_{CTL}=2.7V
● Low insertion loss	0.3dB typ. @f=0.9GHz, P_{IN}=25dBm, V_{CTL}=2.7V
	0.55dB typ. @f=1.9GHz, P_{IN}=25dBm, V_{CTL}=2.7V
● High isolation	21dB typ. @f=0.9GHz, P_{IN}=25dBm, V_{CTL}=2.7V
	15dB typ. @f=1.9GHz, P_{IN}=25dBm, V_{CTL}=2.7V
● Low current consumption	17uA typ. @f=0.9GHz, P_{IN}=25dBm, V_{CTL}=2.7V
● Ultra small & ultra thin package	USB12-E3 (Package size: 2.35x2.35x0.75mm)

■ PIN CONFIGURATION

USB12Type
(Top View)



Pin connection
1. VDD
2. P1
3. GND
4. P2
5. GND
6. P3
7. GND
8. P4
9. GND
10. GND
11. GND
12. CTL

■ TRUTH TABLE

"H"=CTL(H), "L"=CTL(L)

CTL	H	L
P1-P4, P2-P3	ON	OFF
P1-P2, P3-P4	OFF	ON

NOTE: Please note that any information on this catalog will be subject to change.

■ ABSOLUTE MAXIMUM RATINGS

(T_a=+25°C, Z_s=Z_l=50Ω)

PARAMETER	SYMBOL	CONDITIONS	CONDITIONS	UNITS
RF Input Power	P_{IN}	V_{DD} =2.7V, CTL=0V/2.7V	37	dBm
Supply Voltage	V_{DD}	VDD terminal	7.5	V
Control Voltage	V_{CTL}	CTL terminal	7.5	V
Power Dissipation	P_D		250	mW
Operating Temp.	T_{opr}		-40~+85	°C
Storage Temp.	T_{stg}		-55~+150	°C

■ ELECTRICAL CHARACTERISTICS

(General conditions: T_a=+25°C, Z_s=Z_l=50Ω, V_{DD}=2.7V, CTL(L)=0V, CTL(H)=2.7V)

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Operating Current	I_{DD}	P_{IN}=25dBm	-	70	100	uA
Supply Voltage	V_{DD}		-	2.7	5.5	V
Control Voltage (LOW)	CTL(L)		0	-	0.8	V
Control Voltage (HIGH)	CTL(H)		2.5	2.7	V_{DD}	V
Control Current	I_{CTL}	f=0.9GHz, P_{IN}=25dBm	-	17	30	uA
Insertion Loss 1	LOSS1	f=0.9GHz, P_{IN}=25dBm	-	0.3	0.4	dB
Insertion Loss 2	LOSS2	f=1.9GHz, P_{IN}=25dBm	-	0.55	0.7	dB
Isolation 1	ISL1	f=0.9GHz, P_{IN}=25dBm	20	21	-	dB
Isolation 2	ISL2	f=1.9GHz, P_{IN}=25dBm	14	15	-	dB
Pin at 0.2dB Compression Point	$P_{-0.2dB}$	f=1.9GHz	33	36	-	dBm
2nd Harmonics 1	2fo(1)	f=0.9GHz, P_{IN}=25dBm	-	-80	-65	dBc
2nd Harmonics 2	2fo(2)	f=1.9GHz, P_{IN}=25dBm	-	-75	-70	dBc
3rd Harmonics 1	3fo(1)	f=0.9GHz, P_{IN}=25dBm	-	-75	-60	dBc
3rd Harmonics 2	3fo(2)	f=1.9GHz, P_{IN}=25dBm	-	-70	-60	dBc
Input 3rd order intercept Point 1	IIP3(1)	f=900+901MHz, Pin=25dBm *1	56	62	-	dBm
Input 3rd order intercept Point 2	IIP3(2)	f=1900+1901MHz, Pin=25dBm *1	54	60	-	dBm
VSWR	$VSWR_i$	on-state ports, f=0.9GHz	-	1.1	1.4	
Switching time	T_{SW}	f=0.1~2.5GHz	-	1.2	-	us

*1: The input IP3 is defined as following equation.
IIP3=(3 x Pout - IM3) / 2 + LOSS

■ TERMINAL INFORMATION

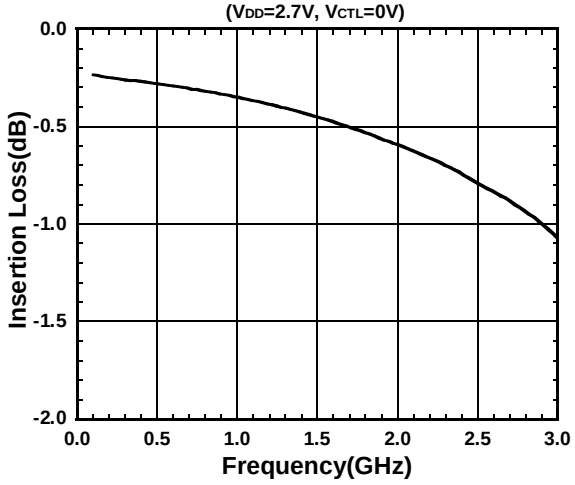
No.	SYMBOL	DESCRIPTION
1	VDD	Positive voltage supply terminal. The positive voltage (+2.5~+5.5V) have to be supplied. Please connect a bypass capacitor with GND terminal for excellent RF performance.
2	P1	RF port. This port is connected with P4 port by controlling 12pin-CTL(H) (+2.5~+VDD). This port is connected with P2 port by controlling 12pin- CTL(L) (0~+0.8V) . A DC cut capacitor 56pF is required at this terminal to block DC voltage of inner circuit.
3	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
4	P2	RF port. This port is connected with P3 port by controlling 12pin- CTL(L) (0.2~+0.8V). This port is connected with P3 port by controlling 12pin- CTL(H)(+2.5~+VDD). A DC cut capacitor 56pF is required at this terminal to block DC voltage of inner circuit.
5	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
6	P3	RF port. This port is connected with P2 port by controlling 12pin- CTL(H) (+2.5~+VDD). This port is connected with P4 port by controlling 12pin-$V_{CTL(L)}$ (0~+0.8V). A DC cut capacitor 56pF is required at this terminal to block DC voltage of inner circuit.
7	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
8	P4	RF port. This port is connected with P1 port by controlling 12pin- CTL(H) (+2.5~+VDD). This port is connected with P3 port by controlling 12pin- CTL(L) (0~+0.8V). A DC cut capacitor 56pF is required at this terminal to block DC voltage of inner circuit.
9	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
10	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
11	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
12	CTL	Control signal input terminal. This terminal is set to High-Level (+2.5V~VDD) or Low-Level (0~+0.8V).

■ ELECTRICAL CHARACTERISTICS

(0.1~3.0GHz, with application circuit, Losses of external circuit are excluded)

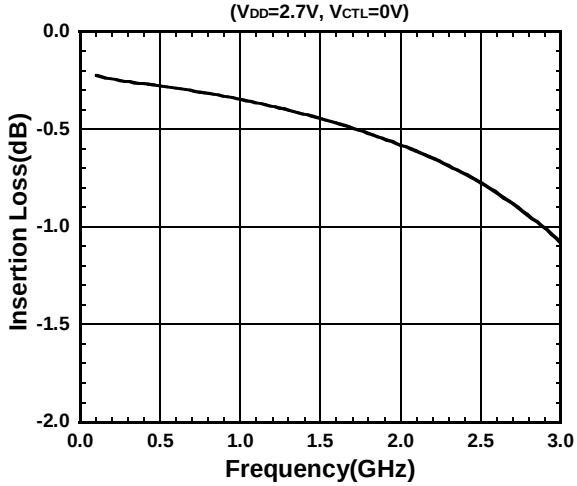
P1-P2 Insertion Loss vs. Frequency

(V_{DD}=2.7V, V_{CTL}=0V)



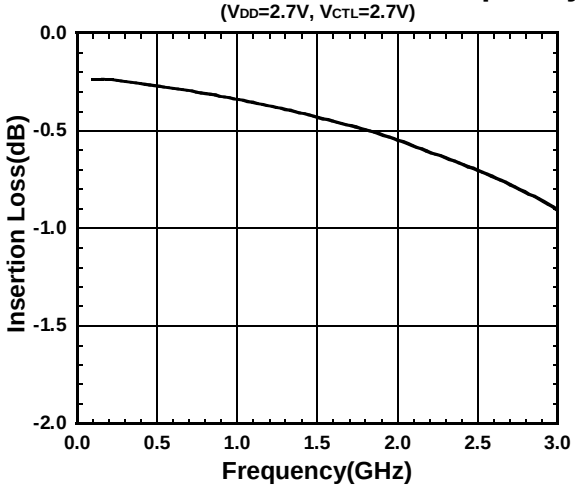
P3-P4 Insertion Loss vs. Frequency

(V_{DD}=2.7V, V_{CTL}=0V)



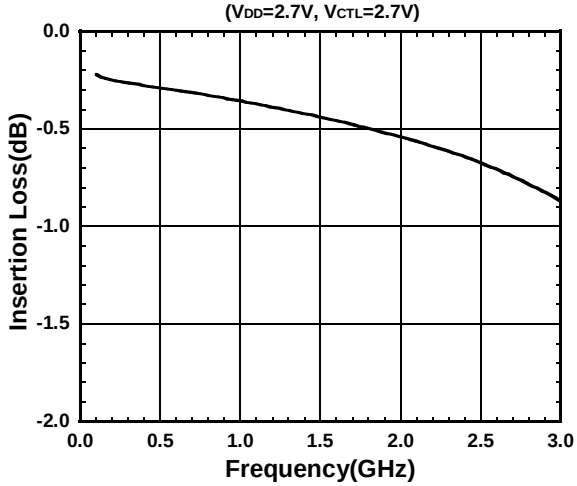
P1-P4 Insertion Loss vs. Frequency

(V_{DD}=2.7V, V_{CTL}=2.7V)



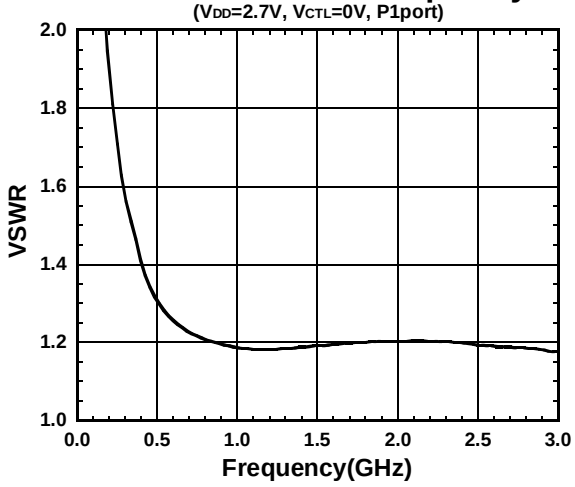
P2-P3 Insertion Loss vs. Frequency

(V_{DD}=2.7V, V_{CTL}=2.7V)



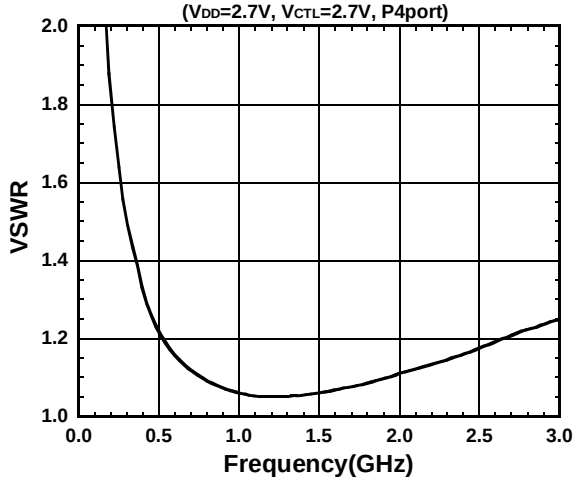
P1-P2 VSWR vs. Frequency

(V_{DD}=2.7V, V_{CTL}=0V, P1port)



P1-P4 VSWR vs. Frequency

(V_{DD}=2.7V, V_{CTL}=2.7V, P4port)

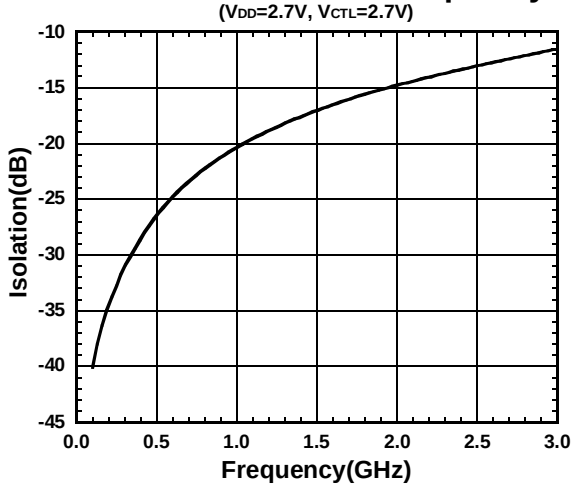


■ ELECTRICAL CHARACTERISTICS

(0.1~3.0GHz, with application circuit, Losses of external circuit are excluded)

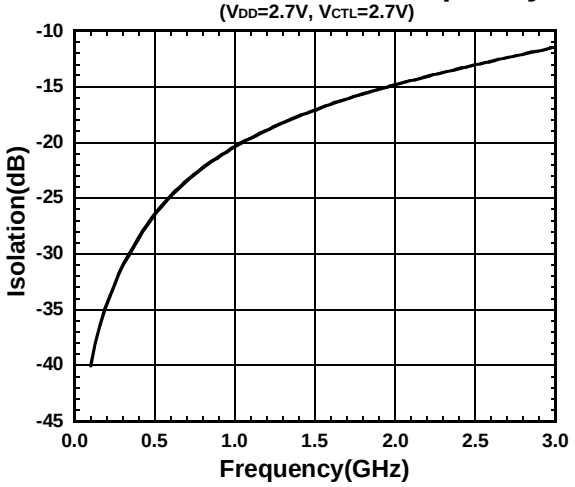
P1-P2 Isolation vs. Frequency

(V_{DD}=2.7V, V_{CTL}=2.7V)



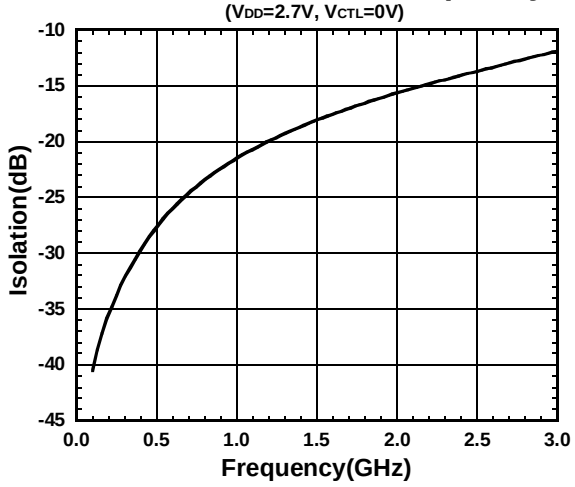
P3-P4 Isolation vs. Frequency

(V_{DD}=2.7V, V_{CTL}=2.7V)



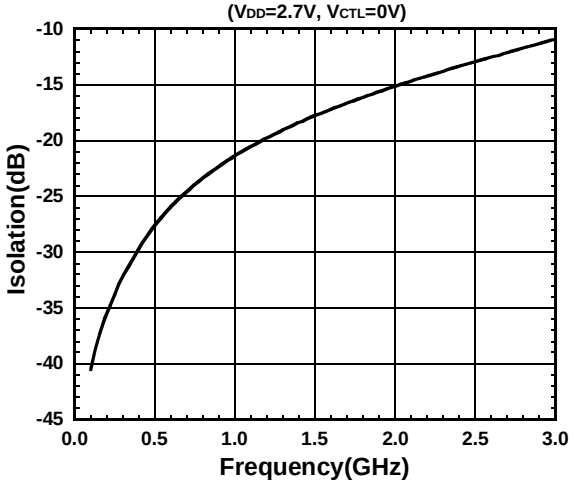
P1-P4 Isolation vs. Frequency

(V_{DD}=2.7V, V_{CTL}=0V)



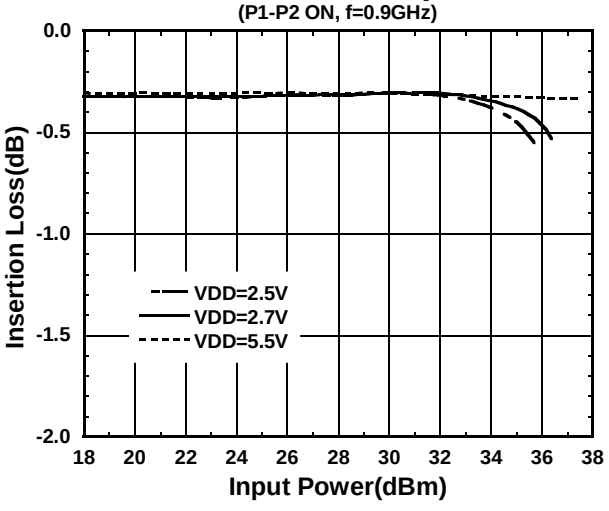
P2-P3 Isolation vs. Frequency

(V_{DD}=2.7V, V_{CTL}=0V)



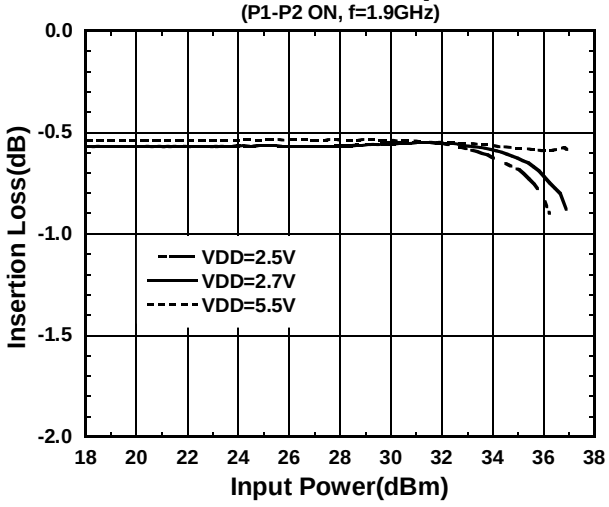
Insertion Loss vs. Input Power

(P1-P2 ON, f=0.9GHz)



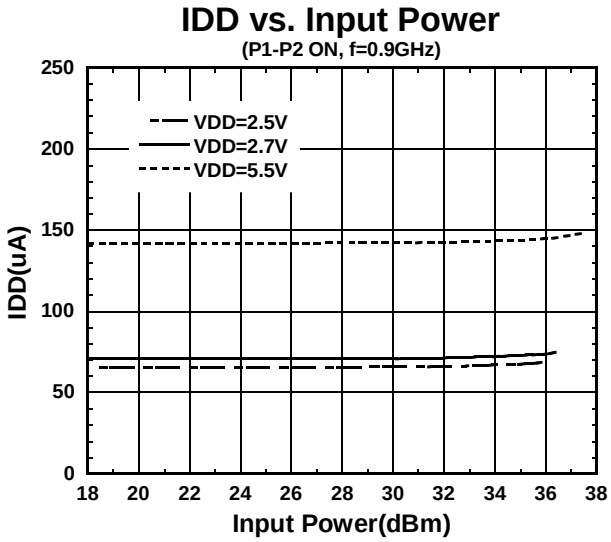
Insertion Loss vs. Input Power

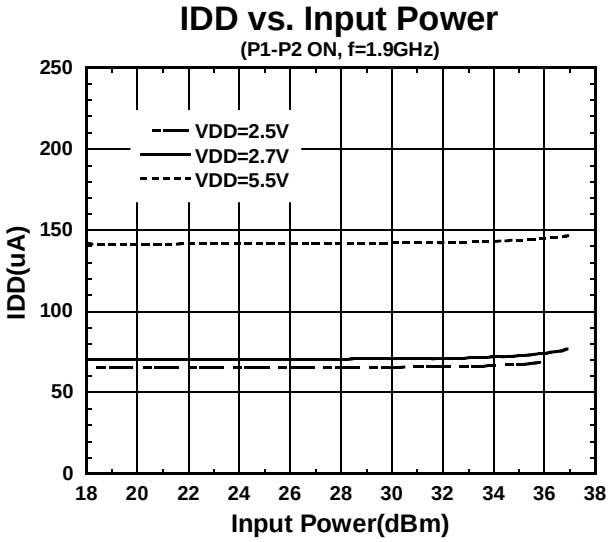
(P1-P2 ON, f=1.9GHz)

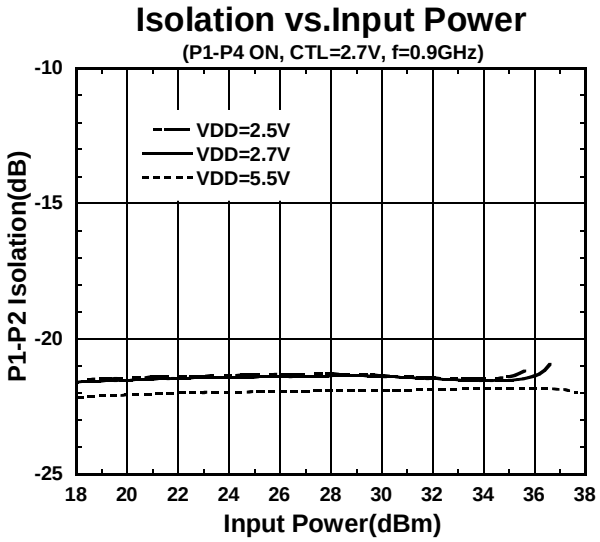


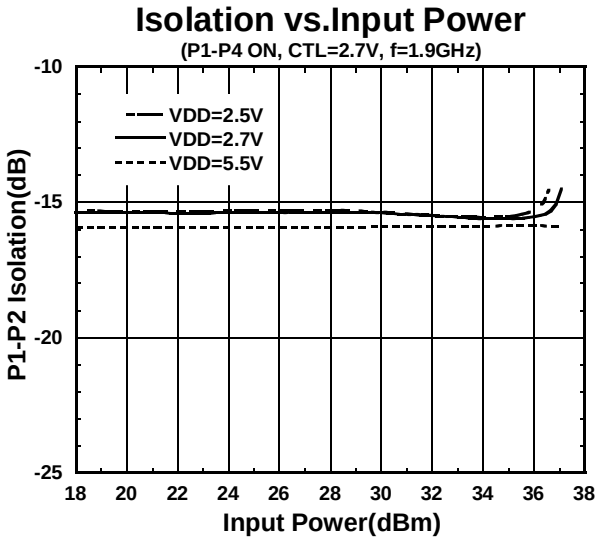
■ ELECTRICAL CHARACTERISTICS

(with application circuit)



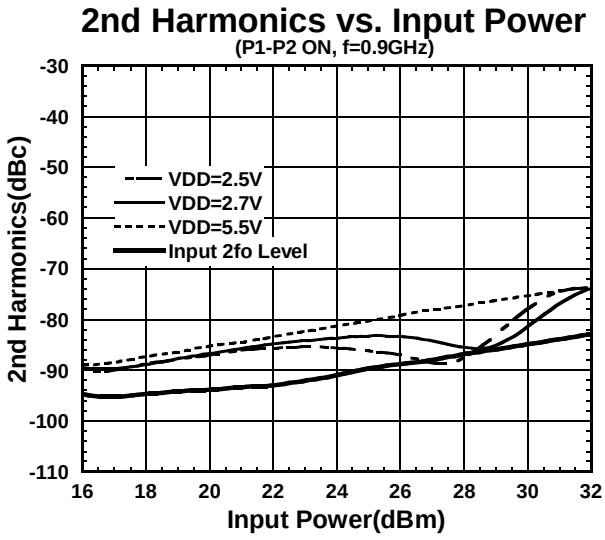


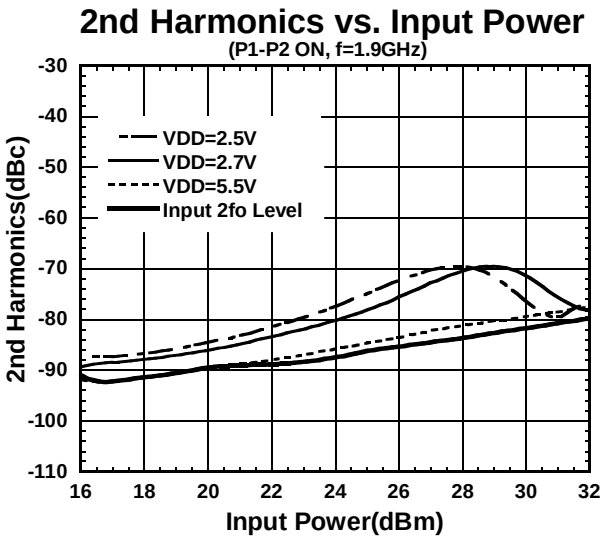


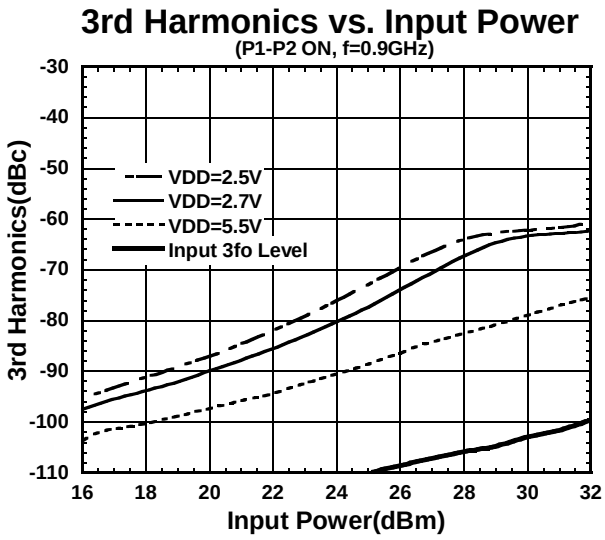


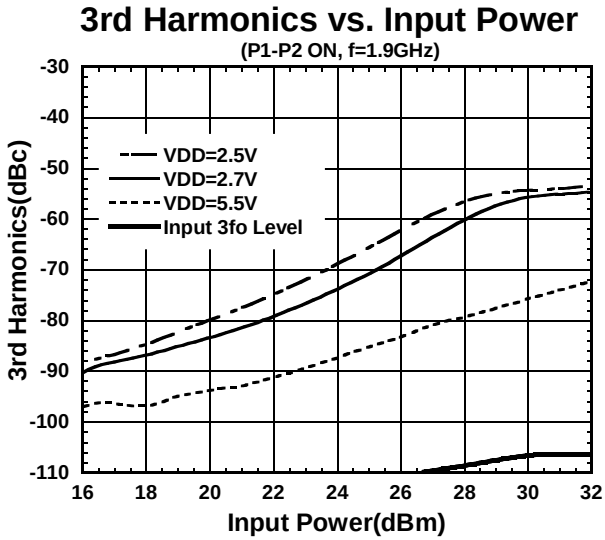
■ ELECTRICAL CHARACTERISTICS

(with application circuit)







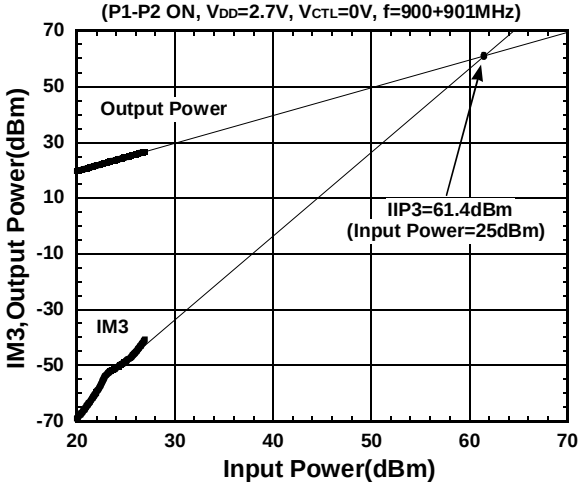


■ ELECTRICAL CHARACTERISTICS

(with application circuit)

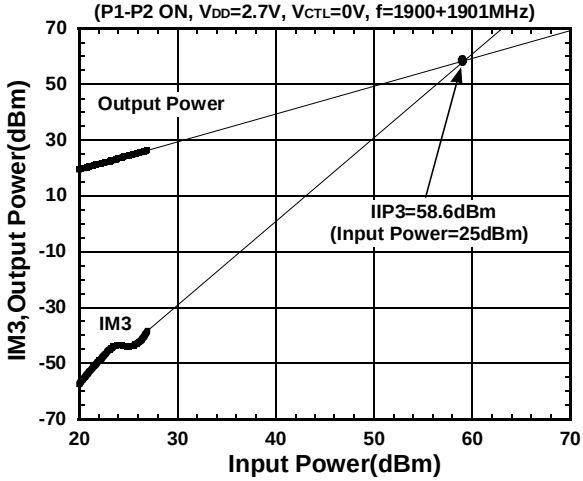
Output Power,IM3 vs. Input Power

(P1-P2 ON, V_{DD}=2.7V, V_{CTL}=0V, f=900+901MHz)



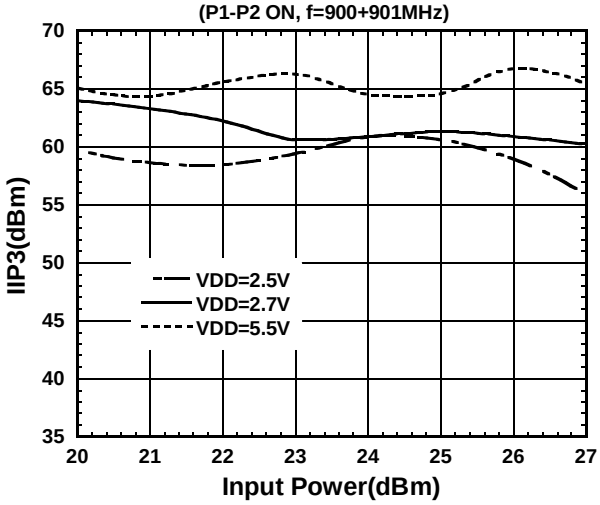
Output Power,IM3 vs. Input Power

(P1-P2 ON, V_{DD}=2.7V, V_{CTL}=0V, f=1900+1901MHz)



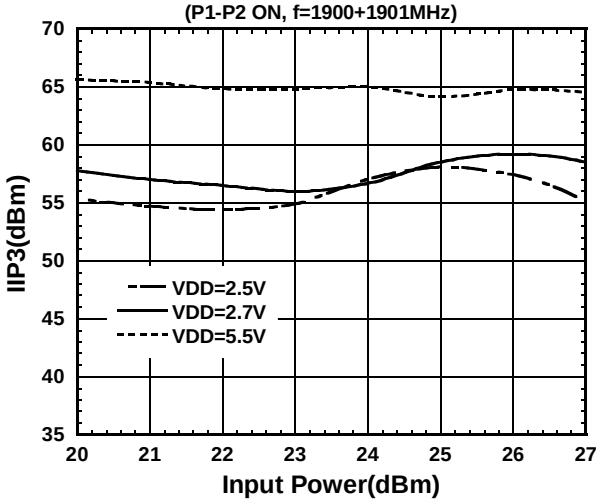
IIP3 vs. Input Power

(P1-P2 ON, f=900+901MHz)



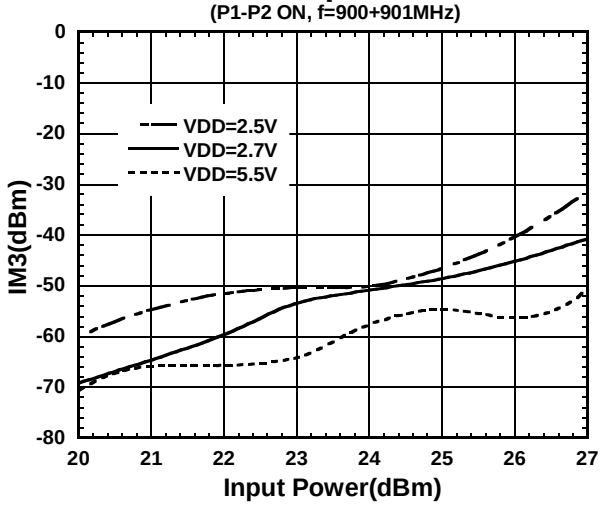
IIP3 vs. Input Power

(P1-P2 ON, f=1900+1901MHz)



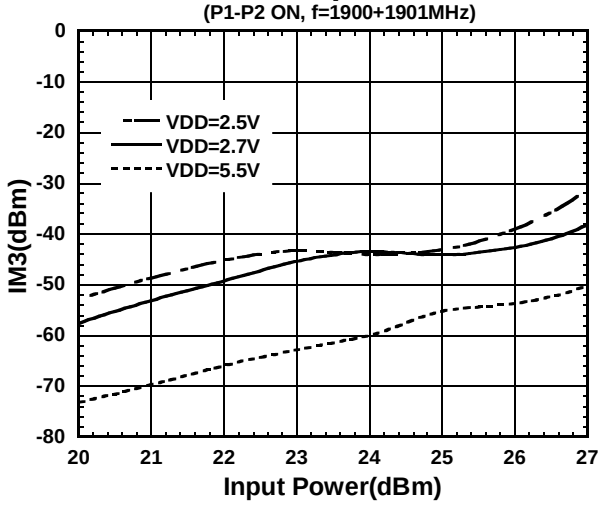
IM3 vs. Input Power

(P1-P2 ON, f=900+901MHz)



IM3 vs. Input Power

(P1-P2 ON, f=1900+1901MHz)

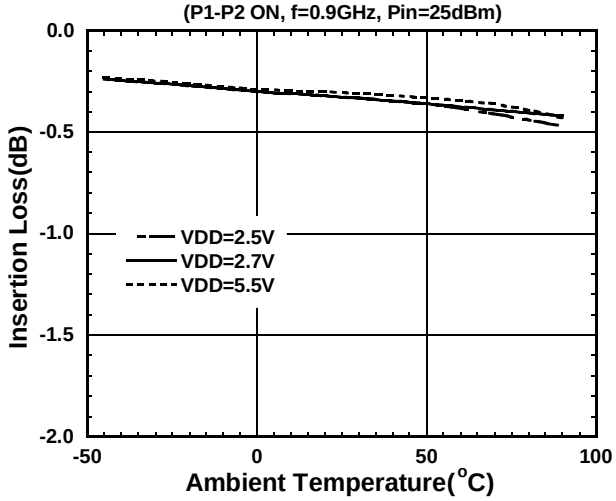


■ ELECTRICAL CHARACTERISTICS

(with application circuit, Losses of external circuit are excluded)

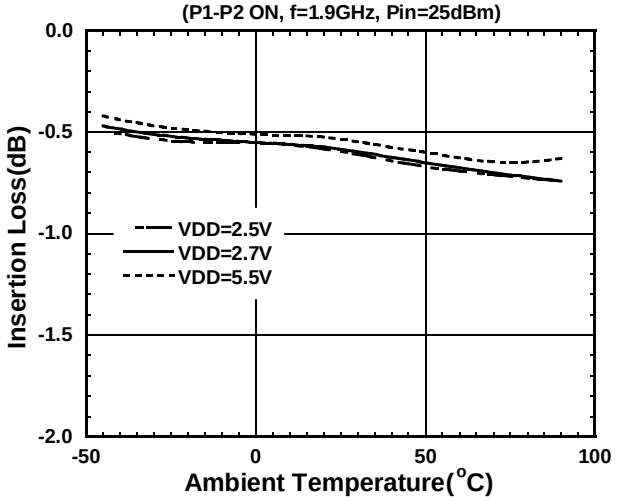
Insertion Loss vs. Ambient Temperature

(P1-P2 ON, f=0.9GHz, Pin=25dBm)



Insertion Loss vs. Ambient Temperature

(P1-P2 ON, f=1.9GHz, Pin=25dBm)

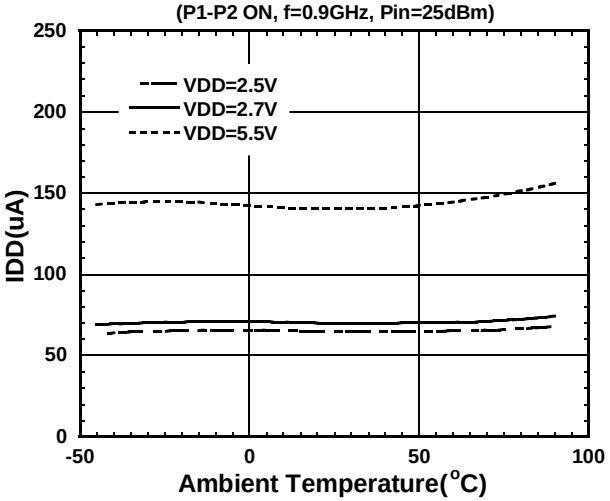


■ ELECTRICAL CHARACTERISTICS

(with application circuit)

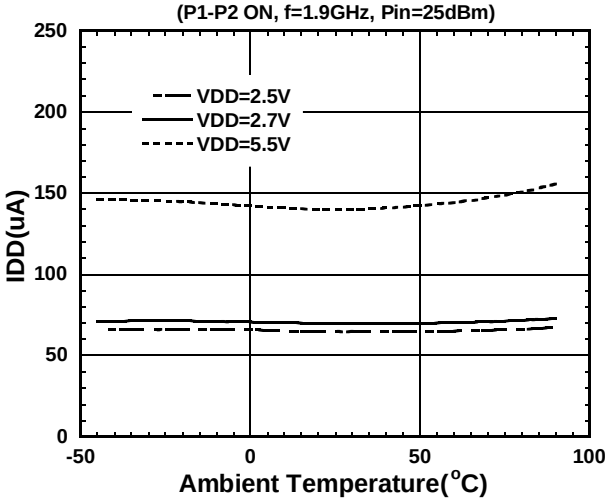
IDD vs. Ambient Temperature

(P1-P2 ON, f=0.9GHz, Pin=25dBm)



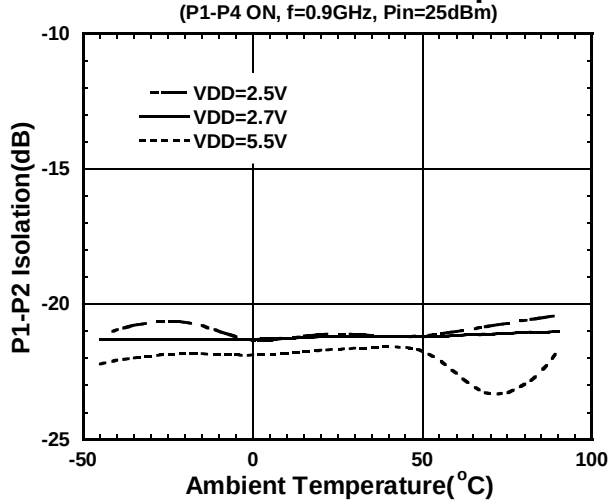
IDD vs. Ambient Temperature

(P1-P2 ON, f=1.9GHz, Pin=25dBm)



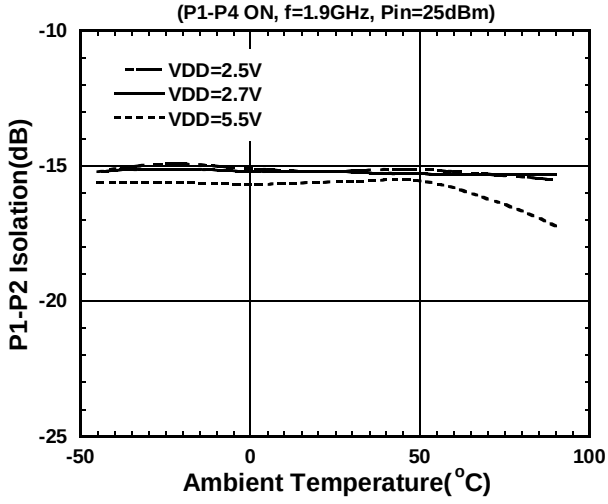
Isolation vs. Ambient Temperature

(P1-P4 ON, f=0.9GHz, Pin=25dBm)



Isolation vs. Ambient Temperature

(P1-P4 ON, f=1.9GHz, Pin=25dBm)

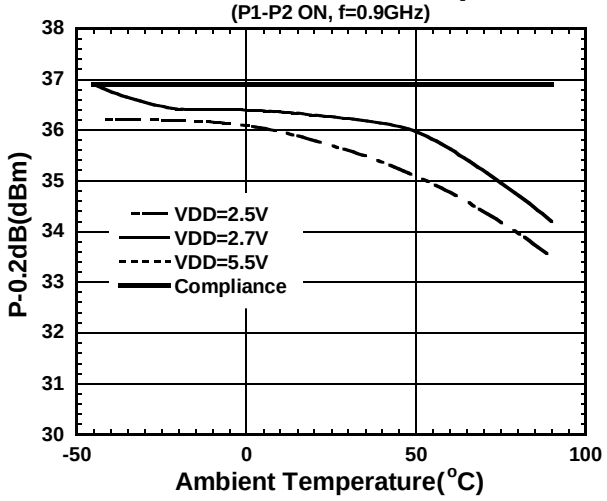


■ ELECTRICAL CHARACTERISTICS

(with application circuit)

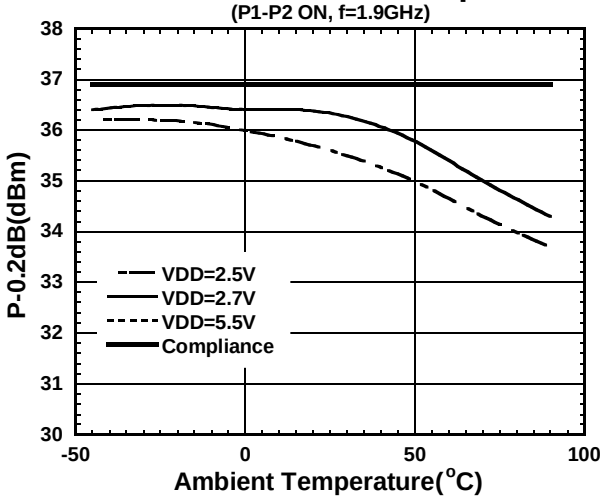
P-0.2dB vs. Ambient Temperature

(P1-P2 ON, f=0.9GHz)



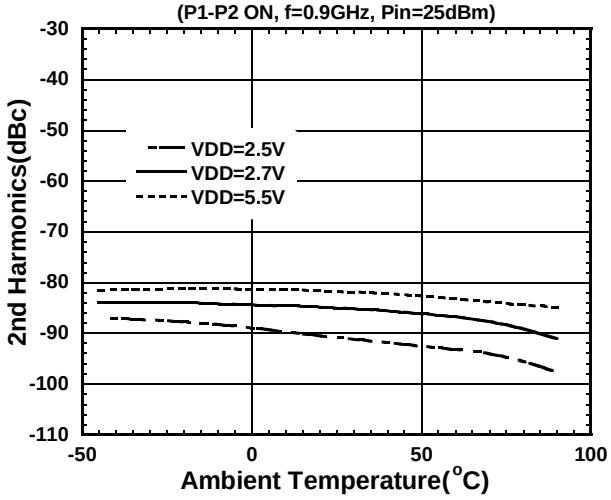
P-0.2dB vs. Ambient Temperature

(P1-P2 ON, f=1.9GHz)



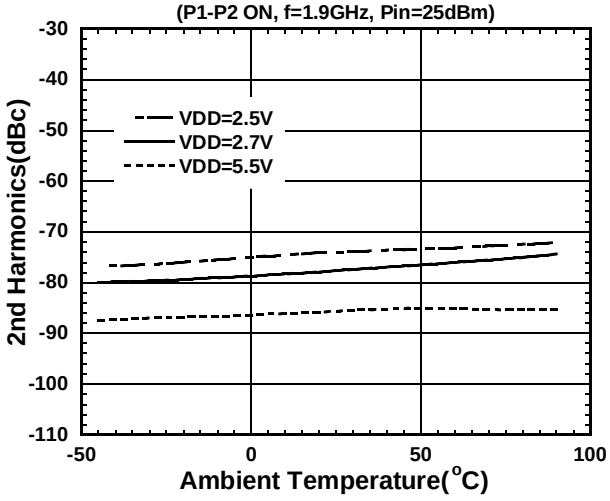
2nd Harmonics vs. Ambient Temperature

(P1-P2 ON, f=0.9GHz, Pin=25dBm)



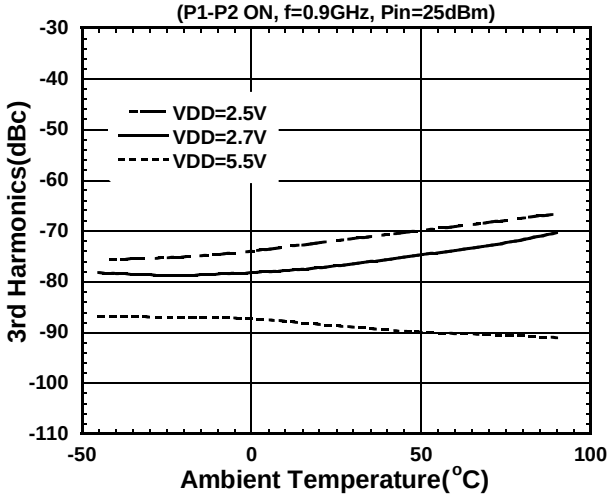
2nd Harmonics vs. Ambient Temperature

(P1-P2 ON, f=1.9GHz, Pin=25dBm)



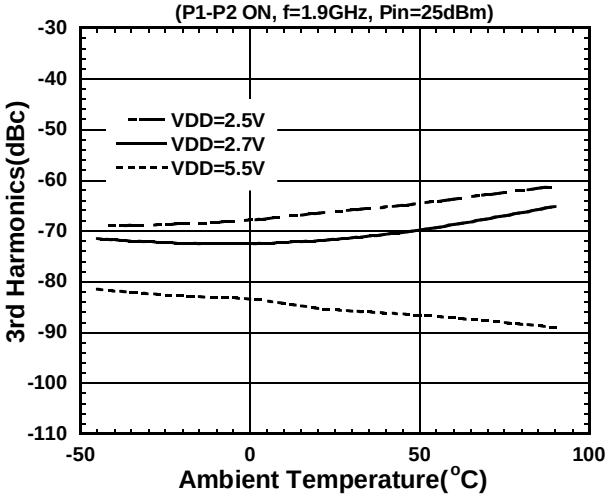
3rd Harmonics vs. Ambient Temperature

(P1-P2 ON, f=0.9GHz, Pin=25dBm)



3rd Harmonics vs. Ambient Temperature

(P1-P2 ON, f=1.9GHz, Pin=25dBm)

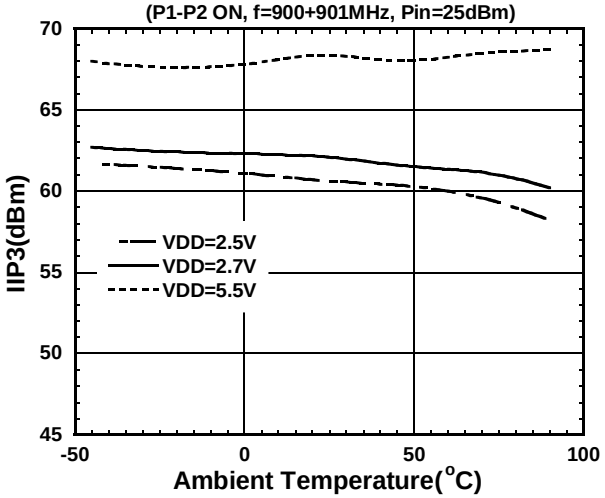


■ ELECTRICAL CHARACTERISTICS

(with application circuit)

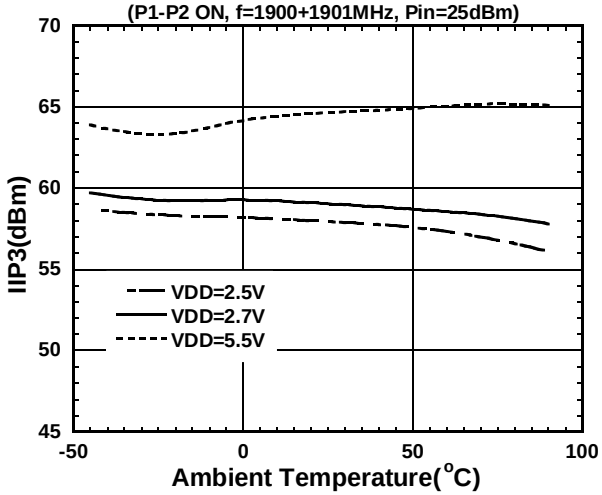
IIP3 vs. Ambient Temperature

(P1-P2 ON, f=900+901MHz, Pin=25dBm)



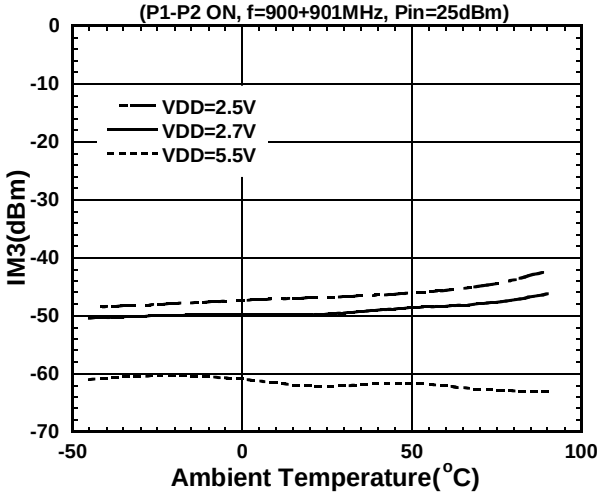
IIP3 vs. Ambient Temperature

(P1-P2 ON, f=1900+1901MHz, Pin=25dBm)



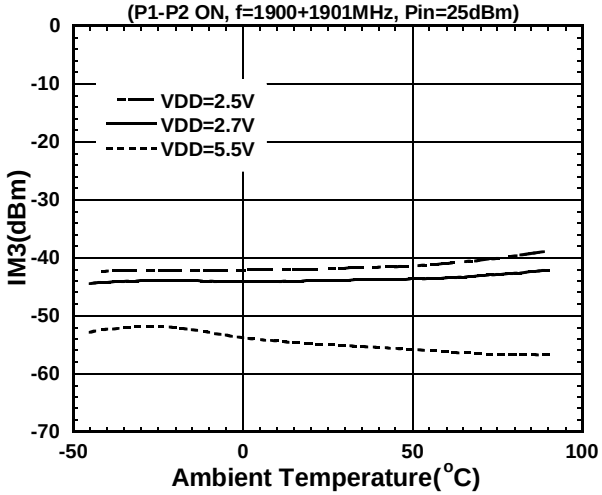
IM3 vs. Ambient Temperature

(P1-P2 ON, f=900+901MHz, Pin=25dBm)



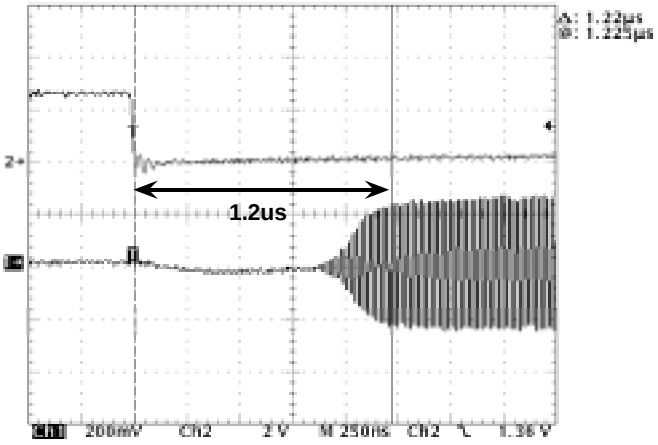
IM3 vs. Ambient Temperature

(P1-P2 ON, f=1900+1901MHz, Pin=25dBm)

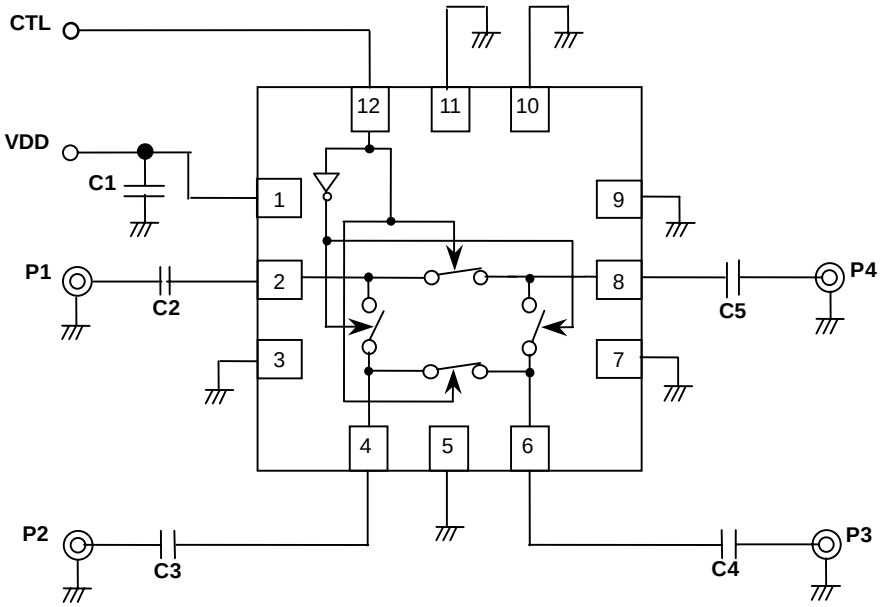


Switching Speed

(Vctl(L)=0V, Vctl(H)=2.7V)



■PACKAGE OUTLINE (USB12-E3)

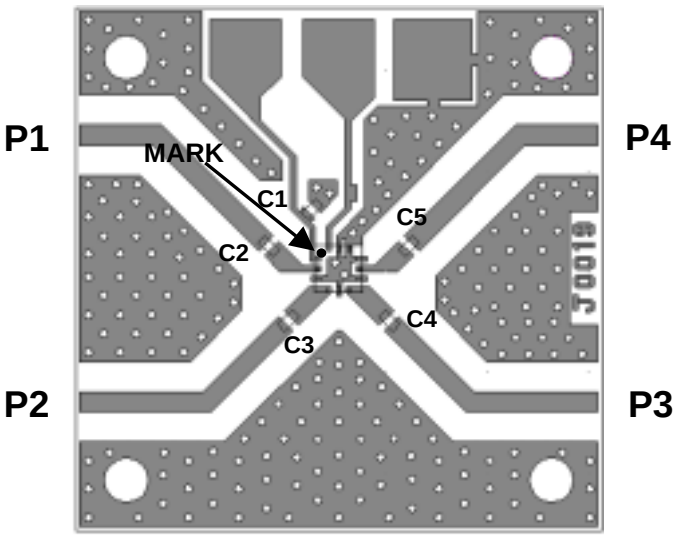


■ PARTS LIST

Parts		Notes
C1	1000pF	MURATA (GRP15)
C2~C5	56pF	MURATA (GRP15)

■RECOMMENDED PCB DESIGN

VDD CTL GND

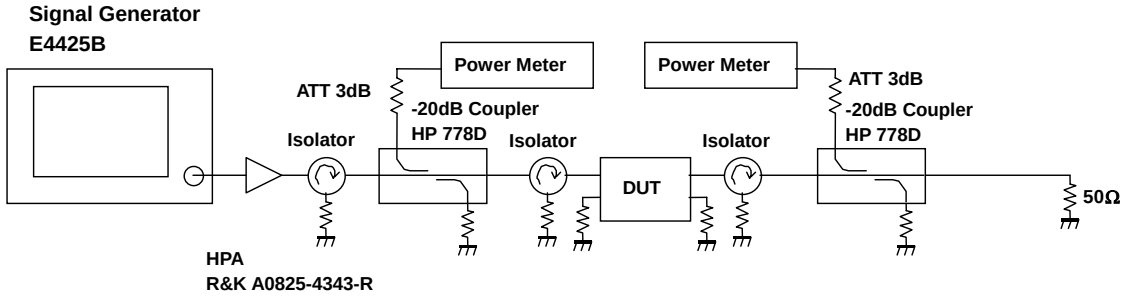


PCB SIZE=26mmX26mm
PCB: FR-4, t=0.5mm
Capacitor: size 1005
Strip line Width=1.0mm (Z_0=50Ω)

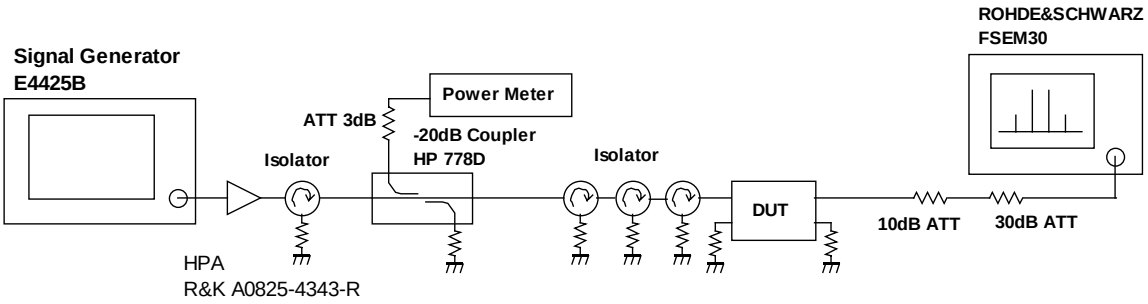
■Circuit losses including losses of capacitors and connectors

Frequency	900MHz	1.9GHz
Loss(dB)	0.20dB	0.32dB

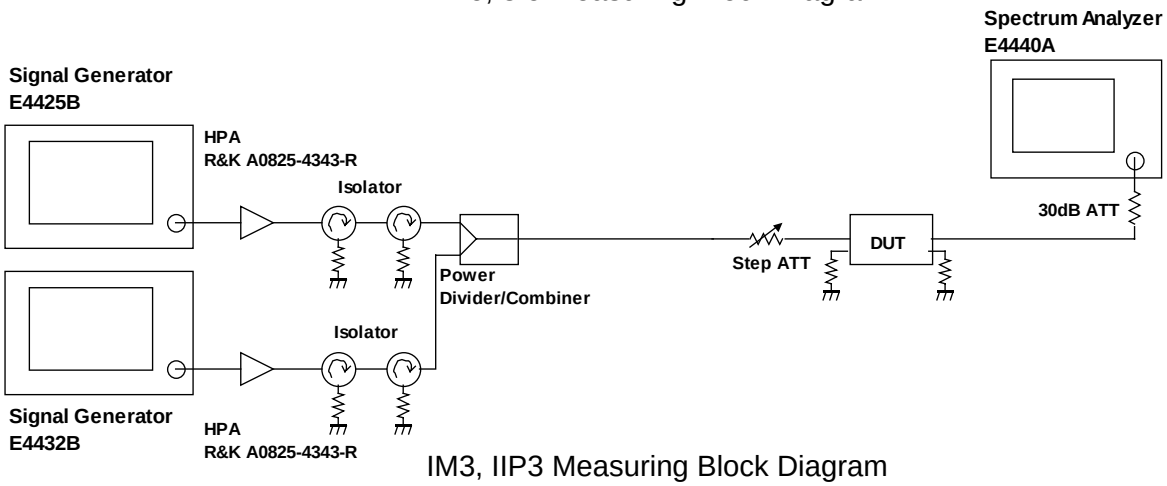
■ MEASURING BLOCK DIAGRAM



Pin-Pout Measuring Block Diagram

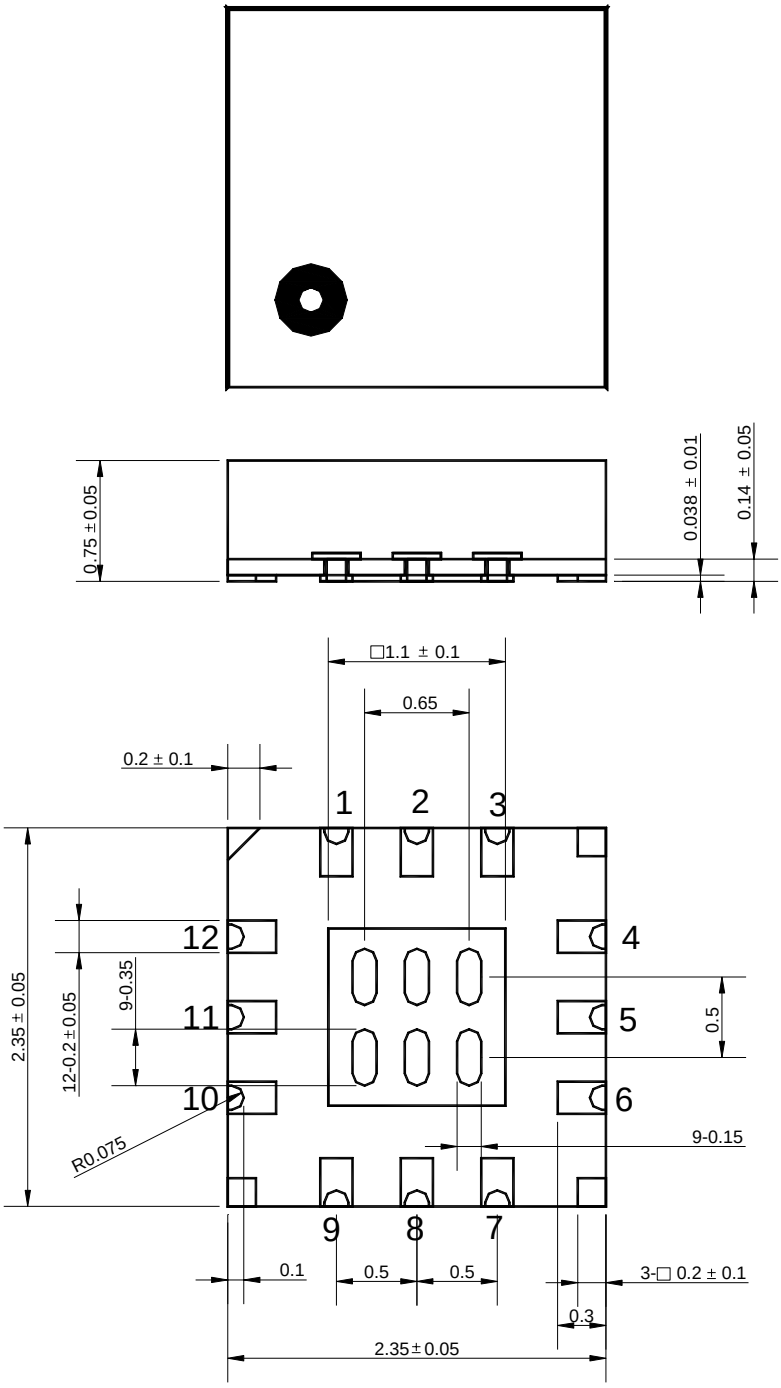


2fo, 3fo Measuring Block Diagram



IM3, IIP3 Measuring Block Diagram

■ PACKAGE OUTLINE(USB12-E3)



NAL TREAT :Au
:FR5
Molding material : Epoxy resin
UNIT :mm
WEIGHT :17mg

Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

[CAUTION]
The specifications on this databook are only given for information , without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

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Поставка электронных компонентов

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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AVIC JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).

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